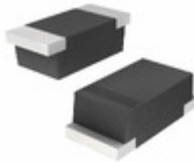
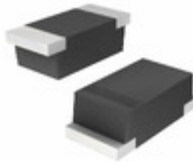
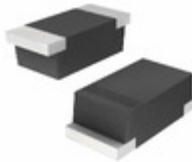
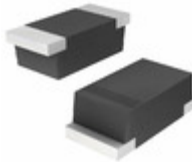
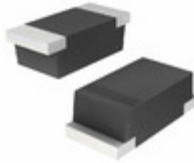
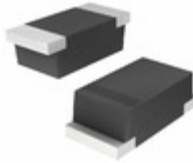
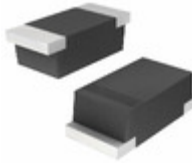
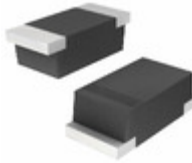


specificazioni	
Numero di parte	CSFMT107-HF
fabbricante	Comchip Technology
Descrizione	DIODE GEN PURP 500V 1A SOD123H
Categoria	Prodotti a semiconduttore discreti > Diodi-raddrizzatori-
Stato parte	33245 pcs Stock
Tensione - diretta (Vf) (max) a If	1.7V @ 1A
Tensione - inversa (Vr) (max)	500V
Contenitore dispositivo fornitore	SOD-123H
Velocità	Fast Recovery = 200mA (Io)
Serie	-
Tempo di ripristino inverso (trr)	35ns
imballaggio	Tape & Reel (TR)
Contenitore / involucro	SOD-123H
Temperatura di funzionamento - Giunzione	-55°C ~ 150°C
Tipo montaggio	Surface Mount
Tipo diodo	Standard
Corrente - Dispersione inversa a Vr	5µA @ 500V
Corrente - raddrizzata media (Io)	1A
Capacità a Vr, F	10pF @ 4V, 1MHz

 CSFMT102-HF Comchip Technology DIODE GEN PURP 100V 1A SOD123H	 CSFMT104-HF Comchip Technology DIODE GEN PURP 200V 1A SOD123H	 CSFMT108-HF Comchip Technology DIODE GEN PURP 600V 1A SOD123H	 CSFMT103-HF Comchip Technology DIODE GEN PURP 150V 1A SOD123H
 CSFMT107-HF Comchip Technology DIODE GEN PURP 500V 1A SOD123H	 CSFMT102-HF Comchip Technology DIODE GEN PURP 100V 1A SOD123H	 CSFMT105-HF Comchip Technology DIODE GEN PURP 300V 1A SOD123H	 CSFMT106-HF Comchip Technology DIODE GEN PURP 400V 1A SOD123H

Di Più

Contact us: **Info@YIC-Electronics.com**

AGGIUNGI: Unit A5-B5 No.509, 5 / F Sing Win Factory Building, 15-17 Shing yip St, Kwun Tong, Kowloon, Hong Kong.

Copyright © 2023 YIC-Electronics.com - YIC International Co., Limited